

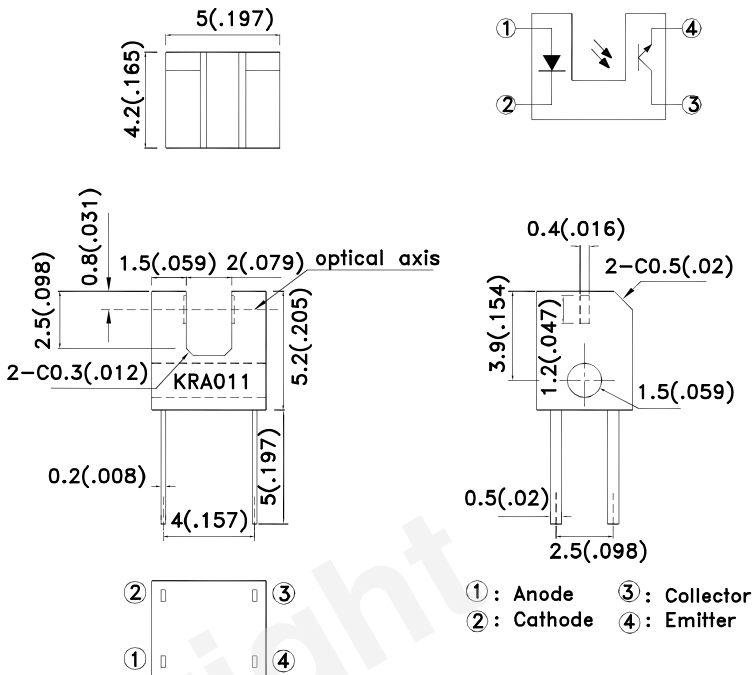
SUBMINIATURE, HIGH SENSITIVITY PHOTOINTERRUPTER

*Features

- 1.Ultra-compact.
- 2.PWBmounting type package.
- 3.High sensing accuracy (Slit width:0.4mm).
- 4.Gap between light emitter and detector:2mm.
- 5.RoHS Compliant.

*Applications

- Cassette tape recorders,VCRs.
- Floppy disk drives.
- Various microcomputerized control equipment.



UNIT : MM[INCH]
TOLERANCE : $\pm 0.25[\pm 0.01]$ UNLESS OTHERWISE NOTED.

Note:
The specifications, characteristics and technical data described in the datasheet are subject to change without prior notice.

*Absolute Maximum Ratings ($T_A=25^\circ\text{C}$)

Parameter		Symbol	Rating	Unit
Input	Forward current	I_F	50	mA
	Reverse voltage	V_R	6	V
	Power dissipation	P_d	75	mW
	Peak Forward Current (Pulse Width $\leq 100\mu\text{s}$, Duty Cycle=1%)	I_{FP}	1	A
Output	Collector-emitter voltage	V_{CEO}	35	V
	Emitter-collector voltage	V_{ECO}	6	V
	Collector current	I_c	20	mA
	Collector power dissipation	P_c	75	mW
Operating Temperature		T_{opr}	-25~+85	$^\circ\text{C}$
Storage Temperature		T_{stg}	-40~+100	$^\circ\text{C}$
Soldering Temperature (1/16 inch from body for 5 seconds)		T_{sol}	260	$^\circ\text{C}$



Electrical / Optical Characteristics at $T_A=25^\circ\text{C}$

Parameter			Symbol	Conditions	Min.	Typ.	Max.	Unit
Input	Forward voltage		V_F	$I_F=20\text{mA}$	1.0	1.2	1.5	V
	Reverse current		I_R	$V_R=6\text{V}$	-	-	10	μA
	Peak Wavelength		λ_p	$I_F=20\text{mA}$	-	940	-	nm
Output	Collector dark current		I_{CEO}	$V_{CE}=20\text{V}$	-	-	100	nA
Transfer Characteristics	Collector-emitter saturation voltage		$V_{CE(SAT)}$	$I_C=40\mu\text{A}$, $I_F=10\text{mA}$	-	-	0.4	V
	Current transfer ratio		CTR	$V_{CE}=5\text{V}$, $I_F=5\text{mA}$	-	8	-	%
	Response time	Rise time	t_r	$V_{CE}=5\text{V}$, $I_C=0.1\text{mA}$, $R_L=1\text{K}\Omega$	-	50	150	μSec
		Fall time	t_f		-	50	150	μSec

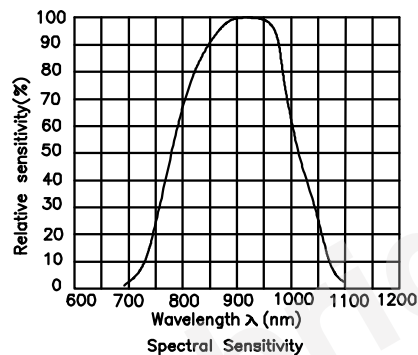


Fig.1 FORWARD CURRENT Vs. FORWARD VOLTAGE

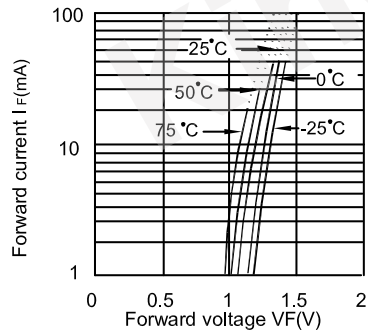


Fig.2 COLLECTOR CURRENT Vs. FORWARD CURRENT

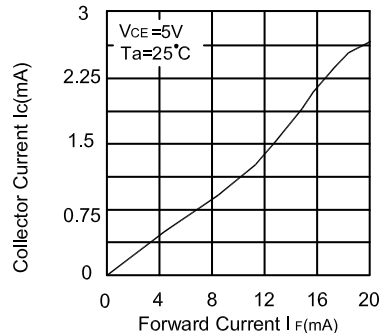


Fig.3 COLLECTOR CURRENT Vs. COLLECTOR-EMITTER VOLTAGE

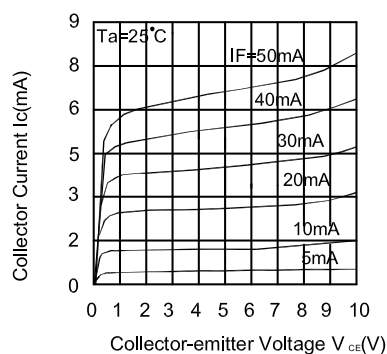


Fig.4 COLLECTOR CURRENT Vs. AMBIENT TEMPERATURE

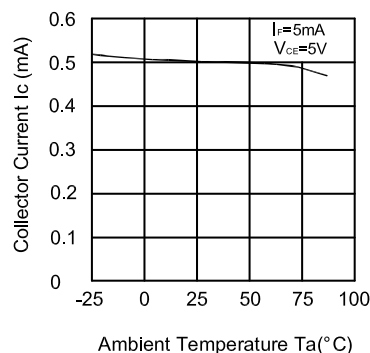


Fig.5 COLLECTOR-EMITTER SATURATION VOLTAGE Vs. AMBIENT TEMPERATURE

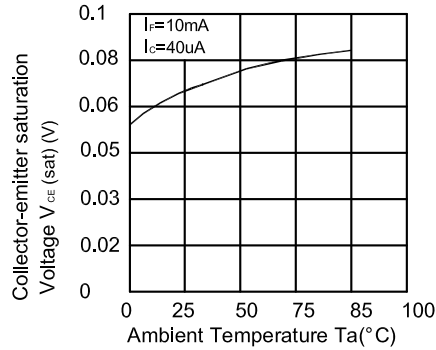


Fig.6 COLLECTOR DARK CURRENT VS. AMBIENT TEMPERATURE

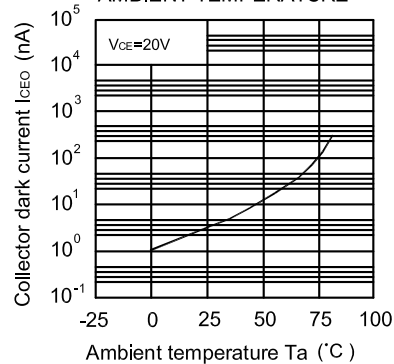


Fig.7 RELATIVE COLLECTOR CURRENT Vs. SHIELD DISTANCE (1)

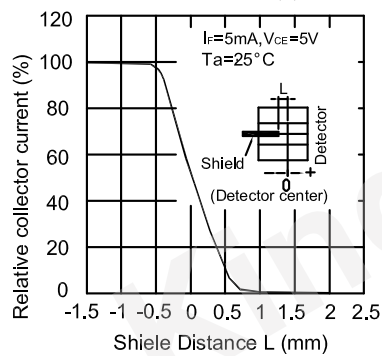


Fig.8 RELATIVE COLLECTOR CURRENT Vs. SHIELD DISTANCE (2)

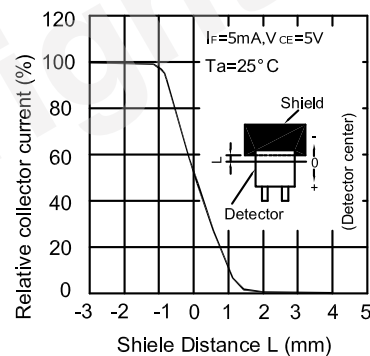
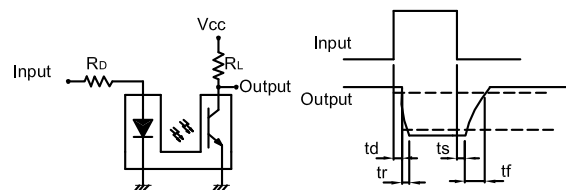
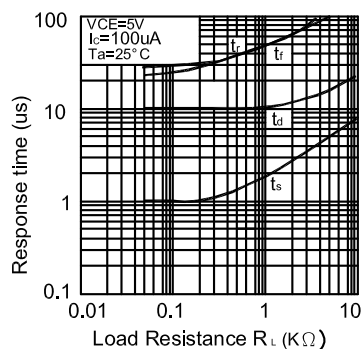
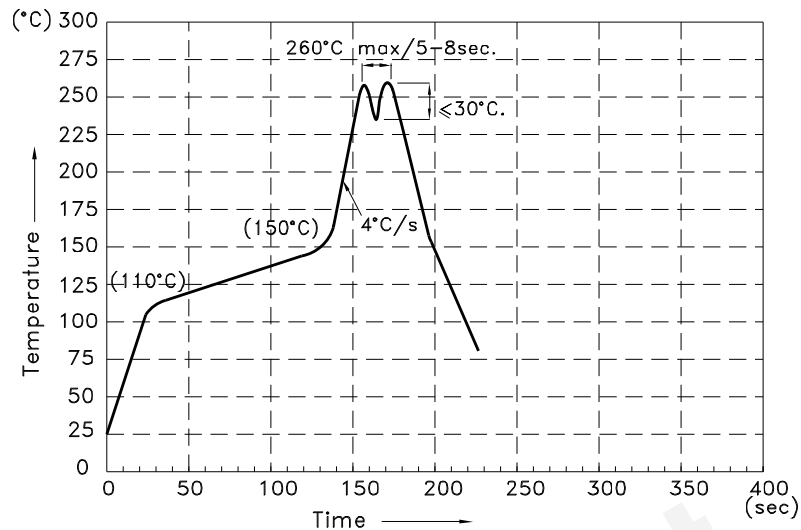


Fig.9 RESPONSE TIME Vs. LOAD RESISTANCE



Test Circuit for Response Time

Wave Soldering Profile For Lead-free Through-hole LED.

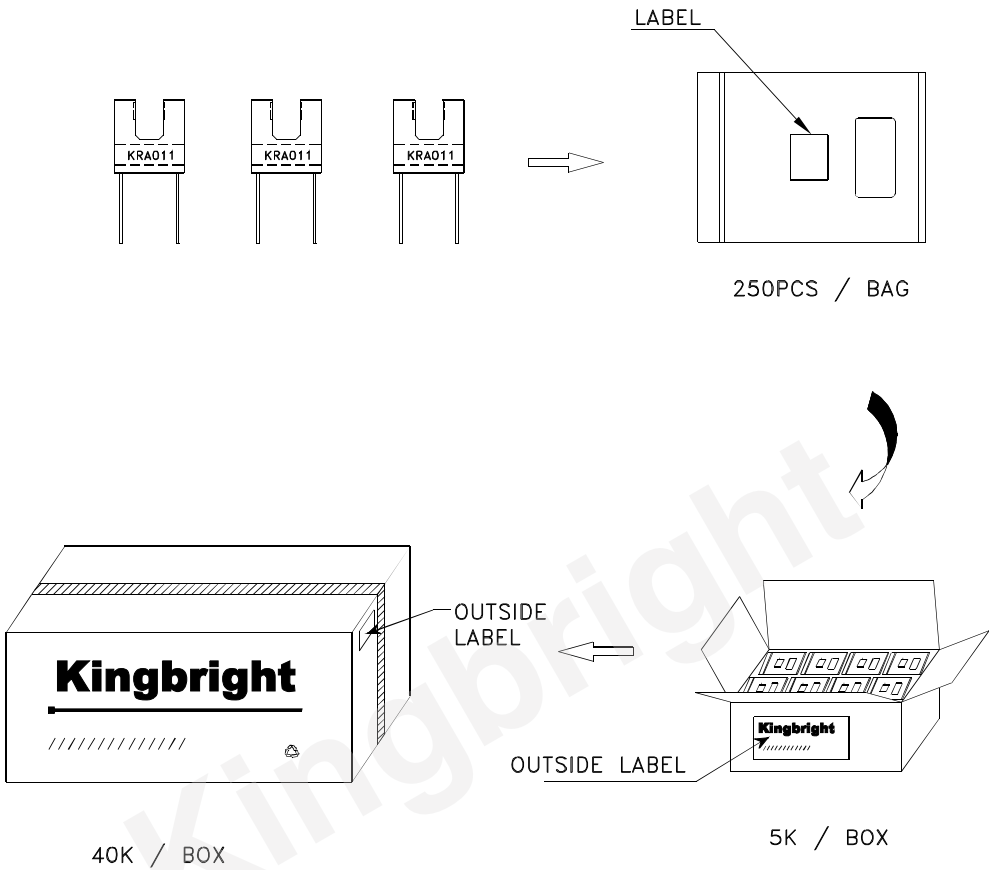


NOTES:

1. Recommend the wave temperature $245^{\circ}\text{C} \sim 260^{\circ}\text{C}$. The maximum soldering temperature should be less than 260°C .
2. Do not apply stress on epoxy resins when temperature is over 85°C .
3. The soldering profile apply to the lead free soldering (Sn/Cu/Ag alloy).
4. No more than once.

PACKING & LABEL SPECIFICATIONS

KRA011



Kingbright		
P/NO: KRAxxx		
QTY: 250 pcs	Q.C.	Q C xx xx xxxx PASSED
S/N: XXXX		
CODE: XXX		
LOT NO:		
 xxxxxxxxxxxxxxxxxxxxxxxxxxxxxxxx		
RoHS Compliant		